## Silicon Power <br> Schottky Diode

$$
\begin{aligned}
& V_{R R M}=20 \mathrm{~V}-40 \mathrm{~V} \\
& \mathrm{I}_{\mathrm{F}(\mathrm{AV})}=500 \mathrm{~A}
\end{aligned}
$$

## Features

- High Surge Capability
- Types from 20 V to $40 \mathrm{~V} \mathrm{~V}_{\text {RRM }}$
- Not ESD Sensitive


Twin Tower Package


Maximum ratings, at $T_{j}=25^{\circ} \mathrm{C}$, unless otherwise specified (" $\mathrm{R}^{\prime \prime}$ devices have leads reversed)

| Parameter | Symbol | Conditions | MBR50020CT(R) | MBR50030CT(R) | MBR50035CT(R) | MBR50040CT(R) | Unit |
| :--- | :--- | :--- | :---: | :--- | :--- | :--- | :--- |
| Repetitive peak reverse <br> voltage | $\mathrm{V}_{\text {RRM }}$ | 20 | 30 | 35 | 40 |  |  |
| RMS reverse voltage | $\mathrm{V}_{\mathrm{RMS}}$ | 14 | 21 | 25 | V |  |  |
| DC blocking voltage | $\mathrm{V}_{\mathrm{DC}}$ | 20 | 30 | 35 | V |  |  |
| Operating temperature | $\mathrm{T}_{\mathrm{j}}$ | -55 to 150 | -55 to 150 | -55 to 150 | -55 to 150 | ${ }^{\circ} \mathrm{C}$ |  |
| Storage temperature | $\mathrm{T}_{\mathrm{stg}}$ | -55 to 150 | -55 to 150 | -55 to 150 | -55 to 150 | ${ }^{\circ} \mathrm{C}$ |  |

Electrical characteristics, at $\mathrm{Tj}=25^{\circ} \mathrm{C}$, unless otherwise specified

| Parameter | Symbol | Conditions | MBR50020CT(R) | MBR50030CT(R) | MBR50035CT(R) | MBR50040CT(R) | Unit |
| :--- | :--- | :--- | :---: | :---: | :---: | :---: | :---: | :---: |
| Average forward current <br> (per pkg) | $\mathrm{I}_{\mathrm{F}(\mathrm{AV})}$ | $\mathrm{T}_{\mathrm{C}}=125^{\circ} \mathrm{C}$ | 500 | 500 | 500 | 500 | A |
| Peak forward surge <br> current (per leg) | $\mathrm{I}_{\mathrm{FSM}}$ | $\mathrm{t}_{\mathrm{p}}=8.3 \mathrm{~ms}$, half sine | 3500 | 3500 | 3500 | 3500 |  | MBR50020CT thru MBR50040CTR



Instantaneous Forward Voltage-Volts



Figure .4- Typical Reverse Characteristics


Reverse Voltage - Volts(\%)

## Package dimensions and terminal configuration

Product is marked with part number and terminal configuration.


| DIM | Inches |  | Millimeters |  |
| :---: | :---: | :---: | :---: | :---: |
|  | Min | Max | Min | Max |
| A | ---* | 3.630 | $\cdots$ | 92.40 |
| B | 0.700 | 0.800 | 17.78 | 20.32 |
| C | ---* | 0.650 | $\cdots$ | 16.51 |
| E | 0.130 | 0.141 | 3.30 | 3.60 |
| F | 0.482 | 0.490 | 12.25 | 12.45 |
| G | 1.368 | BSC | 34.75 | BSC |
| N | 1/4-20 UNC FULL |  |  |  |
| Q | 0.275 | 0.290 | 6.99 | 7.37 |
| R | 3.150 | BSC | 80.01 | BSC |
| U | 0.600 | $\cdots$ | 15.24 | $\cdots$ |
| V | 0.312 | 0.370 | 7.92 | 9.40 |
| W | 0.180 | 0.195 | 4.57 | 4.95 |

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